BGD712C 750 MHz, 18.5 dB gain power doubler amplifier Rev. 3 – 29 September 2010 P

**Product data sheet** 

## 1. Product profile

## 1.1 General description

Hybrid high dynamic range amplifier module in SOT115J package operating at a supply voltage of 24 V (DC).

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

## **1.2 Features and benefits**

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability

#### **1.3 Applications**

I<sub>tot</sub>

• CATV systems operating in the 40 MHz to 750 MHz frequency range.

## 1.4 Quick reference data

total current

# Table 1. Quick reference dataSymbolParameterConditionsMinTyp $G_p$ power gainf = 45 MHz18.2-f = 750 MHz19-

[1] The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

 $V_{B} = 24 V$ 



Unit

dB

dB

mΑ

Max

18.8

20

410

[1] 380

-

750 MHz, 18.5 dB gain power doubler amplifier

## 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	input		
2	common		5
3	common		$\frac{1}{9}$
5	+V <sub>B</sub>		2378
7	common		2 3 7 8 sym095
8	common		
9	output		

## 3. Ordering information

Table 3. Ordering information					
Type number	Package	Package			
	Name	Description	Version		
BGD712C	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J		

## 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
VB	supply voltage		-	30	V
Vi	input voltage		-	70	dBmV
T <sub>stg</sub>	storage temperature		-40	+100	°C
T <sub>mb</sub>	mounting base temperature		-20	+100	°C

2 of 8

750 MHz, 18.5 dB gain power doubler amplifier

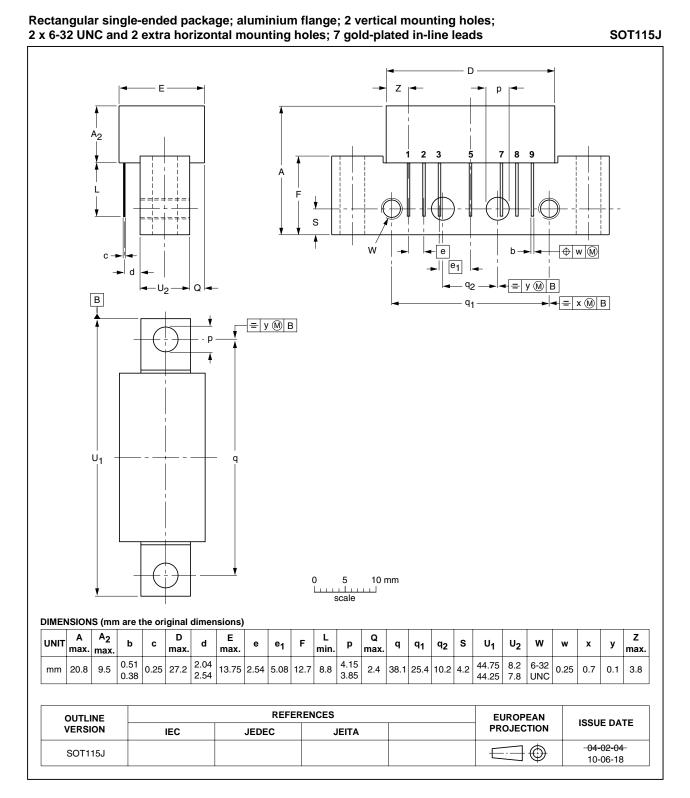
## 5. Characteristics

Table 5.CharacteristicsBandwidth 40 MHz to 750 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75 \Omega$ .						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 45 MHz	18.2	-	18.8	dB
		f = 750 MHz	19.0	-	20.0	dB
SL	slope cable equivalent	f = 45 MHz to 750 MHz	0.5	-	1.5	dB
FL	flatness of frequency response	f = 45  MHz to 100 MHz	-	-	±0.35	dB
		f = 100 MHz to 700 MHz	-	-	±0.5	dB
		f = 700 MHz to 750 MHz	-	-	±0.15	dB
S <sub>11</sub>	input return losses	f = 45 MHz to 790 MHz	17	-	-	dB
S <sub>22</sub>	output return losses	f = 45 MHz to 790 MHz	17	-	-	dB
Φs21	phase response	f = 50 MHz	135	-	225	deg
CTB composite triple beat	composite triple beat	112 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-	-62	dB
	60 channels flat; V <sub>o</sub> = 44 dBmV measured at 745.25 MHz	-	-67	-	dB	
		79 channels flat; V <sub>o</sub> = 44 dBmV measured at 547.25 MHz	-	-	-68	dB
	composite second-order distortion	112 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	-	-	-63	dB
		60 channels flat; V <sub>o</sub> = 44 dBmV measured at 746.5 MHz	-	-70	-	dB
		79 channels flat; V <sub>o</sub> = 44 dBmV measured at 548.5 MHz	-	-	-68	dB
NF	noise figure	f = 50 MHz	-	-	7	dB
		f = 750 MHz	-	-	7	dB
I <sub>tot</sub>	total current		<u>[1]</u> 380	-	410	mA

[1] The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

750 MHz, 18.5 dB gain power doubler amplifier

## 6. Package outline



#### Fig 1. Package outline SOT115J

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BGD712C

## 750 MHz, 18.5 dB gain power doubler amplifier

## 7. Revision history

Table 6.Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BGD712C v.3	20100929	Product data sheet	-	BGD712C v.2
Modifications:		of this data sheet has been of NXP Semiconductors.	en redesigned to comp	ly with the new identity
	<ul> <li>Legal texts</li> </ul>	have been adapted to the	e new company name	where appropriate.
	<ul> <li>Package o</li> </ul>	utline drawings have beer	updated to the latest	version.
BGD712C v.2	20070816	Product data sheet	-	BGD712C v.1
BGD712C v.1	20060502	Product data sheet	_	-

#### 750 MHz, 18.5 dB gain power doubler amplifier

## 8. Legal information

#### 8.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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6 of 8

#### 750 MHz, 18.5 dB gain power doubler amplifier

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#### 750 MHz, 18.5 dB gain power doubler amplifier

## **10. Contents**

1	Product profile 1
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Limiting values 2
5	Characteristics 3
6	Package outline 4
7	Revision history 5
8	Legal information 6
8.1	Data sheet status 6
8.2	Definitions
8.3	Disclaimers 6
8.4	Trademarks 7
9	Contact information 7
10	Contents 8

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